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| Details | |
|--------------------------------|------------------------------------------------------------|
| Product Status | Obsolete |
| Number of LABs/CLBs | 359200 |
| Number of Logic Elements/Cells | 952000 |
| Total RAM Bits | 53248000 |
| Number of I/O | 696 |
| Number of Gates | - |
| Voltage - Supply | 0.82V ~ 0.88V |
| Mounting Type | Surface Mount |
| Operating Temperature | 0°C ~ 85°C (TJ) |
| Package / Case | 1517-BBGA, FCBGA |
| Supplier Device Package | 1517-HBGA (45x45) |
| Purchase URL | https://www.e-xfl.com/product-detail/intel/5sgxeabk3h40c4n |

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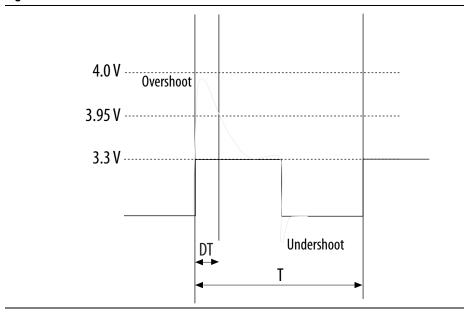
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Table 5 lists the maximum allowed input overshoot voltage and the duration of the overshoot voltage as a percentage of device lifetime. The maximum allowed overshoot duration is specified as a percentage of high time over the lifetime of the device. A DC signal is equivalent to 100% of the duty cycle. For example, a signal that overshoots to 3.95 V can be at 3.95 V for only ~21% over the lifetime of the device; for a device lifetime of 10 years, the overshoot duration amounts to ~2 years.

Table 5. Maximum Allowed Overshoot During Transitions

| Symbol | Description | Condition (V) | Overshoot Duration as % @ T _J = 100°C | Unit |
|---------|------------------|---------------|-----------------------------------------------------|------|
| | | 3.8 | 100 | % |
| | AC input voltage | 3.85 | 64 | % |
| | | 3.9 | 36 | % |
| | | 3.95 | 21 | % |
| Vi (AC) | | 4 | 12 | % |
| | | 4.05 | 7 | % |
| | | 4.1 | 4 | % |
| | | 4.15 | 2 | % |
| | | 4.2 | 1 | % |

Figure 1. Stratix V Device Overshoot Duration



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Table 6. Recommended Operating Conditions for Stratix V Devices (Part 2 of 2)

| Symbol | Description | Condition | Min ⁽⁴⁾ | Тур | Max ⁽⁴⁾ | Unit |
|--------|------------------------|--------------|--------------------|-----|--------------------|------|
| t | Power supply ramp time | Standard POR | 200 μs | _ | 100 ms | _ |
| LRAMP | Fower Supply ramp time | Fast POR | 200 μs | _ | 4 ms | _ |

Notes to Table 6:

- (1) V_{CCPD} must be 2.5 V when V_{CCIO} is 2.5, 1.8, 1.5, 1.35, 1.25 or 1.2 V. V_{CCPD} must be 3.0 V when V_{CCIO} is 3.0 V.
- (2) If you do not use the design security feature in Stratix V devices, connect V_{CCBAT} to a 1.2- to 3.0-V power supply. Stratix V power-on-reset (POR) circuitry monitors V_{CCBAT}. Stratix V devices will not exit POR if V_{CCBAT} stays at logic low.
- (3) C2L and I2L can also be run at 0.90 V for legacy boards that were designed for the C2 and I2 speed grades.
- (4) The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.

Table 7 lists the transceiver power supply recommended operating conditions for Stratix V GX, GS, and GT devices.

Table 7. Recommended Transceiver Power Supply Operating Conditions for Stratix V GX, GS, and GT Devices (Part 1 of 2)

| Symbol | Description | Devices | Minimum ⁽⁴⁾ | Typical | Maximum ⁽⁴⁾ | Unit | |
|------------------------|-----------------------------------------------------------------------------------------------|------------|------------------------|---------|------------------------|------|--|
| V _{CCA_GXBL} | Transceiver channel PLL power supply (left | GX, GS, GT | 2.85 | 3.0 | 3.15 | V | |
| (1), (3) | side) | ७४, ७७, ७१ | 2.375 | 2.5 | 2.625 | V | |
| V _{CCA_GXBR} | Transceiver channel PLL power supply (right | GX, GS | 2.85 | 3.0 | 3.15 | V | |
| $(1), (\overline{3})$ | side) | রম, রহ | 2.375 | 2.5 | 2.625 | V | |
| V _{CCA_GTBR} | Transceiver channel PLL power supply (right side) | GT | 2.85 | 3.0 | 3.15 | V | |
| | Transceiver hard IP power supply (left side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V | |
| V _{CCHIP_L} T | Transceiver hard IP power supply (left side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V | |
| | Transceiver hard IP power supply (right side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V | |
| V_{CCHIP_R} | Transceiver hard IP power supply (right side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V | |
| | Transceiver PCS power supply (left side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V | |
| V _{CCHSSI_L} | Transceiver PCS power supply (left side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V | |
| | Transceiver PCS power supply (right side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V | |
| V _{CCHSSI_R} | Transceiver PCS power supply (right side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V | |
| | | | 0.82 | 0.85 | 0.88 | | |
| V _{CCR_GXBL} | Receiver analog power supply (left side) | OV 00 0T | 0.87 | 0.90 | 0.93 | V | |
| (2) | Treceiver arialog power supply (left side) | GX, GS, GT | 0.97 | 1.0 | 1.03 |] ' | |
| | | | 1.03 | 1.05 | 1.07 | | |

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Table 11. OCT Calibration Accuracy Specifications for Stratix V Devices (1) (Part 2 of 2)

| | | | | Calibratio | n Accuracy | | |
|--------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------|------------|------------|----------------|------------|------|
| Symbol | Description | Conditions | C1 | C2,I2 | C3,I3, I3YY | C4,I4 | Unit |
| 50-Ω R _S | Internal series termination with calibration (50- Ω setting) | V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |
| $34\text{-}\Omega$ and $40\text{-}\Omega$ R_S | Internal series termination with calibration (34- Ω and 40- Ω setting) | V _{CCIO} = 1.5, 1.35, 1.25, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |
| 48 - Ω , 60 - Ω , 80 - Ω , and 240 - Ω R _S | Internal series termination with calibration (48- Ω , 60- Ω , 80- Ω , and 240- Ω setting) | V _{CCIO} = 1.2 V | ±15 | ±15 | ±15 | ±15 | % |
| 50-Ω R _T | Internal parallel termination with calibration (50-Ω setting) | V _{CCIO} = 2.5, 1.8, 1.5, 1.2 V | -10 to +40 | -10 to +40 | -10 to +40 | -10 to +40 | % |
| $\begin{array}{c} 20\text{-}\Omega,30\text{-}\Omega,\\ 40\text{-}\Omega,60\text{-}\Omega,\\ \text{and}\\ 120\text{-}\OmegaR_T \end{array}$ | Internal parallel termination with calibration (20- Ω , 30- Ω , 40- Ω , 60- Ω , and 120- Ω setting) | V _{CCIO} = 1.5, 1.35, 1.25 V | -10 to +40 | -10 to +40 | -10 to +40 | -10 to +40 | % |
| 60- Ω and 120- Ω R _T | Internal parallel termination with calibration (60- Ω and 120- Ω setting) | V _{CCIO} = 1.2 | -10 to +40 | -10 to +40 | -10 to +40 | -10 to +40 | % |
| $\begin{array}{c} \textbf{25-}\Omega \\ \textbf{R}_{S_left_shift} \end{array}$ | Internal left shift series termination with calibration (25- Ω R _{S_left_shift} setting) | V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |

Note to Table 11:

Table 12 lists the Stratix V OCT without calibration resistance tolerance to PVT changes.

Table 12. OCT Without Calibration Resistance Tolerance Specifications for Stratix V Devices (Part 1 of 2)

| | | | Re | esistance | Tolerance | ! | |
|-----------------------------|------------------------------------------------------------------------|-----------------------------------|------------|-----------|-----------------|--------|------|
| Symbol | Description | Conditions | C 1 | C2,I2 | C3, I3, I3YY | C4, I4 | Unit |
| 25-Ω R, 50-Ω R _S | Internal series termination without calibration (25- Ω setting) | V _{CC10} = 3.0 and 2.5 V | ±30 | ±30 | ±40 | ±40 | % |
| 25-Ω R _S | Internal series termination without calibration (25- Ω setting) | V _{CC10} = 1.8 and 1.5 V | ±30 | ±30 | ±40 | ±40 | % |
| 25-Ω R _S | Internal series termination without calibration (25- Ω setting) | V _{CCIO} = 1.2 V | ±35 | ±35 | ±50 | ±50 | % |

⁽¹⁾ OCT calibration accuracy is valid at the time of calibration only.

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Table 13. OCT Variation after Power-Up Calibration for Stratix V Devices (Part 2 of 2) (1)

| Symbol | Description | V _{CCIO} (V) | Typical | Unit | |
|--------|------------------------------------------------------|-----------------------|---------|------|--|
| | | 3.0 | 0.189 | | |
| | OCT variation with temperature without recalibration | 2.5 | 0.208 | | |
| dR/dT | | 1.8 | 0.266 | %/°C | |
| | | 1.5 | 0.273 | | |
| | | 1.2 | 0.317 | | |

Note to Table 13:

(1) Valid for a V_{CCIO} range of $\pm 5\%$ and a temperature range of 0° to $85^\circ\text{C}.$

Pin Capacitance

Table 14 lists the Stratix V device family pin capacitance.

Table 14. Pin Capacitance for Stratix V Devices

| Symbol | Description | Value | Unit |
|--------------------|------------------------------------------------------------------|-------|------|
| C _{IOTB} | Input capacitance on the top and bottom I/O pins | 6 | pF |
| C _{IOLR} | Input capacitance on the left and right I/O pins | 6 | pF |
| C _{OUTFB} | Input capacitance on dual-purpose clock output and feedback pins | 6 | pF |

Hot Socketing

Table 15 lists the hot socketing specifications for Stratix V devices.

Table 15. Hot Socketing Specifications for Stratix V Devices

| Symbol | Description | Maximum |
|---------------------------|--------------------------------------------|---------------------|
| I _{IOPIN (DC)} | DC current per I/O pin | 300 μΑ |
| I _{IOPIN (AC)} | AC current per I/O pin | 8 mA ⁽¹⁾ |
| I _{XCVR-TX (DC)} | DC current per transceiver transmitter pin | 100 mA |
| I _{XCVR-RX (DC)} | DC current per transceiver receiver pin | 50 mA |

Note to Table 15:

(1) The I/O ramp rate is 10 ns or more. For ramp rates faster than 10 ns, $|I_{IOPIN}| = C dv/dt$, in which C is the I/O pin capacitance and dv/dt is the slew rate.

Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 2 of 7)

| Symbol/ | Conditions | Trai | nsceive Grade | r Speed 1 | Transceiver Speed Grade 2 | | | Trai | nsceive Grade | r Speed 3 | Unit |
|---------------------------------------------------------|--------------------------------------------------------|------------------|-----------------------|--------------|------------------------------|---------------------------------------------|------|------|------------------|--------------|-------------|
| Description | | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | |
| Spread-spectrum downspread | PCle | _ | 0 to -0.5 | _ | _ | 0 to -0.5 | _ | _ | 0 to -0.5 | _ | % |
| On-chip termination resistors (21) | _ | _ | 100 | _ | _ | 100 | _ | _ | 100 | _ | Ω |
| Absolute V _{MAX} ⁽⁵⁾ | Dedicated reference clock pin | _ | _ | 1.6 | _ | _ | 1.6 | _ | _ | 1.6 | V |
| | RX reference clock pin | _ | _ | 1.2 | _ | _ | 1.2 | _ | _ | 1.2 | |
| Absolute V _{MIN} | _ | -0.4 | | _ | -0.4 | _ | | -0.4 | _ | 1 | V |
| Peak-to-peak differential input voltage | _ | 200 | _ | 1600 | 200 | | 1600 | 200 | _ | 1600 | mV |
| V _{ICM} (AC coupled) ⁽³⁾ - | Dedicated reference clock pin | 1050/ | 1050/1000/900/850 (2) | | | 1050/1000/900/850 (2) 1050/1000/900/850 (2) | | | | | mV |
| | RX reference clock pin | 1.0/0.9/0.85 (4) | | | 1. | 1.0/0.9/0.85 (4) | | | 1.0/0.9/0.85 (4) | | |
| V _{ICM} (DC coupled) | HCSL I/O standard for PCIe reference clock | 250 | _ | 550 | 250 | _ | 550 | 250 | _ | 550 | mV |
| | 100 Hz | _ | _ | -70 | _ | _ | -70 | _ | _ | -70 | dBc/Hz |
| Transmitter | 1 kHz | _ | _ | -90 | _ | _ | -90 | _ | _ | -90 | dBc/Hz |
| REFCLK Phase Noise | 10 kHz | | _ | -100 | _ | _ | -100 | _ | _ | -100 | dBc/Hz |
| (622 MHz) ⁽²⁰⁾ | 100 kHz | _ | _ | -110 | _ | _ | -110 | _ | _ | -110 | dBc/Hz |
| | ≥1 MHz | _ | _ | -120 | _ | _ | -120 | _ | _ | -120 | dBc/Hz |
| Transmitter REFCLK Phase Jitter (100 MHz) (17) | 10 kHz to 1.5 MHz (PCle) | _ | _ | 3 | _ | _ | 3 | _ | _ | 3 | ps (rms) |
| R _{REF} (19) | _ | _ | 1800 ±1% | _ | _ | 1800 ±1% | _ | _ | 180 0 ±1% | _ | Ω |
| Transceiver Clock | <u> </u> | | | _ | | | _ | | | _ | |
| fixedclk clock frequency | PCIe Receiver Detect | _ | 100 or 125 | _ | _ | 100 or 125 | _ | _ | 100 or 125 | _ | MHz |

Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 4 of 7)

| Symbol/ | Conditions | Tra | nsceive Grade | r Speed 1 | Trai | nsceive Grade | r Speed 2 | Transceiver Speed Grade 3 | | | Unit |
|--------------------------------------------------------|-----------------------------------------------------------------------------|-----|------------------|--------------|------|------------------|--------------|------------------------------|-----------------|-----|------|
| Description | | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | |
| | 85– Ω setting | _ | 85 ± 30% | _ | _ | 85 ± 30% | _ | _ | 85 ± 30% | _ | Ω |
| Differential on- chip termination resistors (21) | 100–Ω setting | _ | 100 ± 30% | | _ | 100 ± 30% | _ | _ | 100 ± 30% | _ | Ω |
| | 120–Ω setting | _ | 120 ± 30% | _ | _ | 120 ± 30% | _ | _ | 120 ± 30% | _ | Ω |
| | 150-Ω setting | _ | 150 ± 30% | _ | _ | 150 ± 30% | _ | _ | 150 ± 30% | _ | Ω |
| V _{ICM} (AC and DC | V _{CCR_GXB} = 0.85 V or 0.9 V full bandwidth | _ | 600 | _ | _ | 600 | _ | _ | 600 | _ | mV |
| | V _{CCR_GXB} = 0.85 V or 0.9 V half bandwidth | _ | 600 | _ | _ | 600 | _ | _ | 600 | _ | mV |
| coupled) | $V_{CCR_GXB} = \\ 1.0 \text{ V/1.05 V} \\ \text{full} \\ \text{bandwidth}$ | _ | 700 | _ | _ | 700 | _ | _ | 700 | _ | mV |
| | V _{CCR_GXB} = 1.0 V half bandwidth | _ | 750 | _ | _ | 750 | _ | _ | 750 | _ | mV |
| t _{LTR} (11) | _ | _ | _ | 10 | _ | _ | 10 | _ | _ | 10 | μs |
| t _{LTD} (12) | _ | 4 | _ | | 4 | | | 4 | | | μs |
| t _{LTD_manual} (13) | _ | 4 | _ | | 4 | | | 4 | | | μs |
| t _{LTR_LTD_manual} (14) | | 15 | | | 15 | | _ | 15 | _ | | μs |
| Run Length | | _ | _ | 200 | _ | | 200 | _ | - | 200 | UI |
| Programmable equalization (AC Gain) (10) | Full bandwidth (6.25 GHz) Half bandwidth (3.125 GHz) | _ | _ | 16 | _ | _ | 16 | _ | _ | 16 | dB |

Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 6 of 7)

| Symbol/ | Conditions | Trai | nsceive Grade | r Speed e 1 | Trar | sceive Grade | r Speed 2 | Tran | sceive Grade | er Speed e 3 | Unit |
|-----------------------------------------------------------------------|----------------------------------------------|------|------------------|-------------------------------|------|-----------------|-------------------------------|------|-----------------|-------------------------------|------|
| Description | | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | |
| Inter-transceiver block transmitter channel-to- channel skew | xN PMA bonded mode | ı | ı | 500 | _ | ı | 500 | _ | _ | 500 | ps |
| CMU PLL | | | | | | | | | | | |
| Supported Data Range | _ | 600 | _ | 12500 | 600 | _ | 12500 | 600 | _ | 8500/ 10312.5 (24) | Mbps |
| t _{pll_powerdown} (15) | _ | 1 | _ | _ | 1 | _ | _ | 1 | _ | _ | μs |
| t _{pll_lock} (16) | _ | _ | _ | 10 | _ | _ | 10 | _ | _ | 10 | μs |
| ATX PLL | | | | | | | | | | | |
| | VCO post-divider L=2 | 8000 | | 14100 | 8000 | | 12500 | 8000 | _ | 8500/ 10312.5 (24) | Mbps |
| Currented Date | L=4 | 4000 | _ | 7050 | 4000 | _ | 6600 | 4000 | _ | 6600 | Mbps |
| Supported Data Rate Range | L=8 | 2000 | _ | 3525 | 2000 | _ | 3300 | 2000 | _ | 3300 | Mbps |
| S | L=8, Local/Central Clock Divider =2 | 1000 | _ | 1762.5 | 1000 | _ | 1762.5 | 1000 | _ | 1762.5 | Mbps |
| t _{pll_powerdown} (15) | _ | 1 | _ | _ | 1 | _ | _ | 1 | _ | _ | μs |
| t _{pll_lock} (16) | _ | | _ | 10 | _ | _ | 10 | _ | _ | 10 | μs |
| fPLL | | | | | | | | | | | |
| Supported Data Range | _ | 600 | _ | 3250/ 3125 ⁽²⁵⁾ | 600 | _ | 3250/ 3125 ⁽²⁵⁾ | 600 | _ | 3250/ 3125 ⁽²⁵⁾ | Mbps |
| t _{pll_powerdown} (15) | _ | 1 | _ | | 1 | _ | | 1 | | | μs |

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Table 25 shows the approximate maximum data rate using the standard PCS.

Table 25. Stratix V Standard PCS Approximate Maximum Date Rate (1), (3)

| Mada (2) | Transceiver | PMA Width | 20 | 20 | 16 | 16 | 10 | 10 | 8 | 8 |
|---------------------|-------------|------------------------------------------|---------|---------|---------|---------|-----|-----|------|------|
| Mode ⁽²⁾ | Speed Grade | PCS/Core Width | 40 | 20 | 32 | 16 | 20 | 10 | 16 | 8 |
| | 1 | C1, C2, C2L, I2, I2L core speed grade | 12.2 | 11.4 | 9.76 | 9.12 | 6.5 | 5.8 | 5.2 | 4.72 |
| | 2 | C1, C2, C2L, I2, I2L core speed grade | 12.2 | 11.4 | 9.76 | 9.12 | 6.5 | 5.8 | 5.2 | 4.72 |
| | 2 | C3, I3, I3L core speed grade | 9.8 | 9.0 | 7.84 | 7.2 | 5.3 | 4.7 | 4.24 | 3.76 |
| FIFO | | C1, C2, C2L, I2, I2L core speed grade | 8.5 | 8.5 | 8.5 | 8.5 | 6.5 | 5.8 | 5.2 | 4.72 |
| | 3 | I3YY core speed grade | 10.3125 | 10.3125 | 7.84 | 7.2 | 5.3 | 4.7 | 4.24 | 3.76 |
| | 3 | C3, I3, I3L core speed grade | 8.5 | 8.5 | 7.84 | 7.2 | 5.3 | 4.7 | 4.24 | 3.76 |
| | | C4, I4 core speed grade | 8.5 | 8.2 | 7.04 | 6.56 | 4.8 | 4.2 | 3.84 | 3.44 |
| | 1 | C1, C2, C2L, I2, I2L core speed grade | 12.2 | 11.4 | 9.76 | 9.12 | 6.1 | 5.7 | 4.88 | 4.56 |
| | 2 | C1, C2, C2L, I2, I2L core speed grade | 12.2 | 11.4 | 9.76 | 9.12 | 6.1 | 5.7 | 4.88 | 4.56 |
| | 2 | C3, I3, I3L core speed grade | 9.8 | 9.0 | 7.92 | 7.2 | 4.9 | 4.5 | 3.96 | 3.6 |
| Register | | C1, C2, C2L, I2, I2L core speed grade | 10.3125 | 10.3125 | 10.3125 | 10.3125 | 6.1 | 5.7 | 4.88 | 4.56 |
| | 3 | I3YY core speed grade | 10.3125 | 10.3125 | 7.92 | 7.2 | 4.9 | 4.5 | 3.96 | 3.6 |
| | 3 - | C3, I3, I3L core speed grade | 8.5 | 8.5 | 7.92 | 7.2 | 4.9 | 4.5 | 3.96 | 3.6 |
| | | C4, I4 core speed grade | 8.5 | 8.2 | 7.04 | 6.56 | 4.4 | 4.1 | 3.52 | 3.28 |

Notes to Table 25:

⁽¹⁾ The maximum data rate is in Gbps.

⁽²⁾ The Phase Compensation FIFO can be configured in FIFO mode or register mode. In the FIFO mode, the pointers are not fixed, and the latency can vary. In the register mode the pointers are fixed for low latency.

⁽³⁾ The maximum data rate is also constrained by the transceiver speed grade. Refer to Table 1 for the transceiver speed grade.

Figure 2 shows the differential transmitter output waveform.

Figure 2. Differential Transmitter Output Waveform

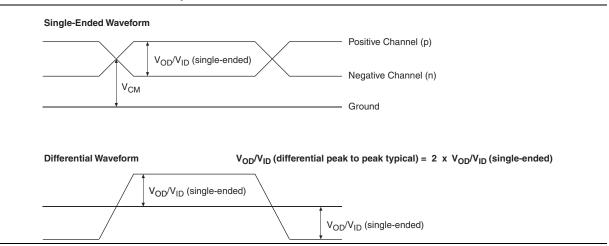


Figure 3 shows the Stratix V AC gain curves for GX channels.

Figure 3. AC Gain Curves for GX Channels (full bandwidth)



Stratix V GT devices contain both GX and GT channels. All transceiver specifications for the GX channels not listed in Table 28 are the same as those listed in Table 23.

Table 28 lists the Stratix V GT transceiver specifications.

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Table 28. Transceiver Specifications for Stratix V GT Devices (Part 1 of 5) $^{(1)}$

| Symbol/ | Conditions | 5 | Transceive Speed Grade | | | Transceive peed Grade | | Unit |
|----------------------------------------------------------------|--------------------------------------------------------|-----------|---------------------------|--------------|------------------------|--------------------------|--------------|------------|
| Description | | Min | Тур | Max | Min | Тур | Max | |
| Reference Clock | • | • | • | • | • | • | • | |
| Supported I/O Standards | Dedicated reference clock pin | 1.2-V PCN | /IL, 1.4-V PC | ML, 1.5-V P | CML, 2.5-V and HCSL | PCML, Diffe | rential LVPE | ECL, LVDS, |
| Standards | RX reference clock pin | | 1.4-V PCML | ., 1.5-V PCN | IL, 2.5-V PC | ML, LVPEC | L, and LVDS | ; |
| Input Reference Clock Frequency (CMU PLL) ⁽⁶⁾ | _ | 40 | _ | 710 | 40 | _ | 710 | MHz |
| Input Reference Clock Frequency (ATX PLL) (6) | _ | 100 | _ | 710 | 100 | _ | 710 | MHz |
| Rise time | 20% to 80% | _ | _ | 400 | _ | _ | 400 | |
| Fall time | 80% to 20% | _ | _ | 400 | _ | <u> </u> | 400 | ps |
| Duty cycle | _ | 45 | _ | 55 | 45 | _ | 55 | % |
| Spread-spectrum modulating clock frequency | PCI Express (PCIe) | 30 | _ | 33 | 30 | _ | 33 | kHz |
| Spread-spectrum downspread | PCle | _ | 0 to -0.5 | _ | _ | 0 to -0.5 | _ | % |
| On-chip termination resistors (19) | _ | _ | 100 | _ | _ | 100 | _ | Ω |
| Absolute V _{MAX} (3) | Dedicated reference clock pin | _ | _ | 1.6 | _ | _ | 1.6 | V |
| | RX reference clock pin | _ | _ | 1.2 | _ | _ | 1.2 | |
| Absolute V _{MIN} | _ | -0.4 | _ | _ | -0.4 | _ | _ | V |
| Peak-to-peak differential input voltage | _ | 200 | _ | 1600 | 200 | _ | 1600 | mV |
| V _{ICM} (AC coupled) | Dedicated reference clock pin | | 1050/1000 | 2) | | 1050/1000 | 2) | mV |
| | RX reference clock pin | 1 | .0/0.9/0.85 | (22) | 1 | .0/0.9/0.85 | (22) | V |
| V _{ICM} (DC coupled) | HCSL I/O standard for PCIe reference clock | 250 | _ | 550 | 250 | _ | 550 | mV |

Table 29 shows the $\ensuremath{V_{\text{OD}}}$ settings for the GT channel.

Table 29. Typical V_{0D} Setting for GT Channel, TX Termination = 100 Ω

| Symbol | V _{op} Setting | V _{op} Value (mV) |
|-------------------------------------------------------------------------|-------------------------|----------------------------|
| | 0 | 0 |
| | 1 | 200 |
| V differential peak to peak tunical (1) | 2 | 400 |
| V _{OD} differential peak to peak typical ⁽¹⁾ | 3 | 600 |
| | 4 | 800 |
| | 5 | 1000 |

Note:

(1) Refer to Figure 4.

Figure 6 shows the Stratix V DC gain curves for GT channels.

Figure 6. DC Gain Curves for GT Channels

Transceiver Characterization

This section summarizes the Stratix V transceiver characterization results for compliance with the following protocols:

- Interlaken
- 40G (XLAUI)/100G (CAUI)
- 10GBase-KR
- QSGMII
- XAUI
- SFI
- Gigabit Ethernet (Gbe / GIGE)
- SPAUI
- Serial Rapid IO (SRIO)
- CPRI
- OBSAI
- Hyper Transport (HT)
- SATA
- SAS
- CEI

Table 33. Memory Block Performance Specifications for Stratix V Devices (1), (2) (Part 2 of 2)

| | | Resour | ces Used | | | Pe | erforman | ce | | | |
|---------------|-----------------------------------------------------------------------------------------------------------|--------|----------|-----|------------|-----|----------|---------|---------------------|-----|------|
| Memory | Mode | ALUTS | Memory | C1 | C2, C2L | C3 | C4 | 12, 12L | 13, 13L, 13YY | 14 | Unit |
| | Single-port, all supported widths | 0 | 1 | 700 | 700 | 650 | 550 | 700 | 500 | 450 | MHz |
| | Simple dual-port, all supported widths | 0 | 1 | 700 | 700 | 650 | 550 | 700 | 500 | 450 | MHz |
| | Simple dual-port with the read-during-write option set to Old Data , all supported widths | 0 | 1 | 525 | 525 | 455 | 400 | 525 | 455 | 400 | MHz |
| M20K Block | Simple dual-port with ECC enabled, 512 × 32 | 0 | 1 | 450 | 450 | 400 | 350 | 450 | 400 | 350 | MHz |
| - | Simple dual-port with ECC and optional pipeline registers enabled, 512 × 32 | 0 | 1 | 600 | 600 | 500 | 450 | 600 | 500 | 450 | MHz |
| | True dual port, all supported widths | 0 | 1 | 700 | 700 | 650 | 550 | 700 | 500 | 450 | MHz |
| | ROM, all supported widths | 0 | 1 | 700 | 700 | 650 | 550 | 700 | 500 | 450 | MHz |

Notes to Table 33:

Temperature Sensing Diode Specifications

Table 34 lists the internal TSD specification.

Table 34. Internal Temperature Sensing Diode Specification

| Tei | mperature Range | Accuracy | Offset Calibrated Option | Sampling Rate | Conversion Time | Resolution | Minimum Resolution with no Missing Codes |
|------|--------------------|----------|--------------------------------|----------------|--------------------|------------|---------------------------------------------------|
| -40° | °C to 100°C | ±8°C | No | 1 MHz, 500 KHz | < 100 ms | 8 bits | 8 bits |

Table 35 lists the specifications for the Stratix V external temperature sensing diode.

Table 35. External Temperature Sensing Diode Specifications for Stratix V Devices

| Description | Min | Тур | Max | Unit |
|------------------------------------------|-------|-------|-------|------|
| I _{bias} , diode source current | 8 | _ | 200 | μΑ |
| V _{bias,} voltage across diode | 0.3 | _ | 0.9 | V |
| Series resistance | _ | _ | <1 | Ω |
| Diode ideality factor | 1.006 | 1.008 | 1.010 | _ |

⁽¹⁾ To achieve the maximum memory block performance, use a memory block clock that comes through global clock routing from an on-chip PLL set to **50%** output duty cycle. Use the Quartus II software to report timing for this and other memory block clocking schemes.

⁽²⁾ When you use the error detection cyclical redundancy check (CRC) feature, there is no degradation in F_{MAX}.

⁽³⁾ The F_{MAX} specification is only achievable with Fitter options, **MLAB Implementation In 16-Bit Deep Mode** enabled.

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Periphery Performance

This section describes periphery performance, including high-speed I/O and external memory interface.

I/O performance supports several system interfaces, such as the **LVDS** high-speed I/O interface, external memory interface, and the **PCI/PCI-X** bus interface. General-purpose I/O standards such as 3.3-, 2.5-, 1.8-, and 1.5-**LVTTL/LVCMOS** are capable of a typical 167 MHz and 1.2-**LVCMOS** at 100 MHz interfacing frequency with a 10 pF load.



The actual achievable frequency depends on design- and system-specific factors. Ensure proper timing closure in your design and perform HSPICE/IBIS simulations based on your specific design and system setup to determine the maximum achievable frequency in your system.

High-Speed I/O Specification

Table 36 lists high-speed I/O timing for Stratix V devices.

Table 36. High-Speed I/O Specifications for Stratix V Devices (1), (2) (Part 1 of 4)

| _ | | | | | | | | | | | | | | |
|--------------------------------------------------------------------------------------------------------|---------------------------------------|-----|-----|-----|-----|--------|--------|-----|---------|------------|-----|------|------------|-------|
| Cumbal | Conditions | | C1 | | C2, | C2L, I | 2, I2L | C3, | 13, I3L | ., I3YY | | C4,I | 4 | Unit |
| Symbol | Conuntions | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | UIIIL |
| f _{HSCLK_in} (input clock frequency) True Differential I/O Standards | Clock boost factor W = 1 to 40 (4) | 5 | | 800 | 5 | _ | 800 | 5 | | 625 | 5 | | 525 | MHz |
| f _{HSCLK_in} (input clock frequency) Single Ended I/O Standards ⁽³⁾ | Clock boost factor W = 1 to 40 (4) | 5 | | 800 | 5 | _ | 800 | 5 | | 625 | 5 | | 525 | MHz |
| f _{HSCLK_in} (input clock frequency) Single Ended I/O Standards | Clock boost factor W = 1 to 40 (4) | 5 | | 520 | 5 | _ | 520 | 5 | | 420 | 5 | | 420 | MHz |
| f _{HSCLK_OUT} (output clock frequency) | _ | 5 | | 800 | 5 | _ | 800 | 5 | | 625 (5) | 5 | | 525 (5) | MHz |

Table 36. High-Speed I/O Specifications for Stratix V Devices (1), (2) (Part 2 of 4)

| Combal | Conditions | | C1 | | C2, | C2L, I | 2, I2L | C3, | I3, I3I | ., I3YY | | C4,I4 | 4 | II.a.i.k |
|---------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------|-----|-----|------|-----|--------|--------|-----|---------|---------|-----|-------|------|----------|
| Symbol | Conditions | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| Transmitter | | | | | | | | | | | | | | |
| | SERDES factor J = 3 to 10 (9), (11), (12), (13), (14), (15), (16) | (6) | _ | 1600 | (6) | _ | 1434 | (6) | _ | 1250 | (6) | _ | 1050 | Mbps |
| True Differential I/O Standards | SERDES factor J ≥ 4 LVDS TX with DPA (12), (14), (15), (16) | (6) | _ | 1600 | (6) | _ | 1600 | (6) | _ | 1600 | (6) | | 1250 | Mbps |
| - f _{HSDR} (data rate) | SERDES factor J = 2, uses DDR Registers | (6) | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | Mbps |
| | SERDES factor J = 1, uses SDR Register | (6) | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | Mbps |
| Emulated Differential I/O Standards with Three External Output Resistor Networks - f _{HSDR} (data rate) (10) | SERDES factor J = 4 to 10 (17) | (6) | _ | 1100 | (6) | _ | 1100 | (6) | _ | 840 | (6) | _ | 840 | Mbps |
| t _{x Jitter} - True Differential | Total Jitter for Data Rate 600 Mbps - 1.25 Gbps | _ | _ | 160 | _ | _ | 160 | _ | _ | 160 | _ | _ | 160 | ps |
| I/O Standards | Total Jitter for Data Rate < 600 Mbps | _ | _ | 0.1 | _ | _ | 0.1 | _ | _ | 0.1 | _ | _ | 0.1 | UI |
| t _{x Jitter} - Emulated Differential I/O Standards with Three External Output Resistor Network | Total Jitter for Data Rate 600 Mbps - 1.25 Gbps | _ | _ | 300 | _ | _ | 300 | _ | _ | 300 | _ | _ | 325 | ps |
| | Total Jitter for Data Rate < 600 Mbps | _ | _ | 0.2 | _ | _ | 0.2 | _ | _ | 0.2 | _ | _ | 0.25 | UI |

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Figure 7 shows the dynamic phase alignment (DPA) lock time specifications with the DPA PLL calibration option enabled.

Figure 7. DPA Lock Time Specification with DPA PLL Calibration Enabled

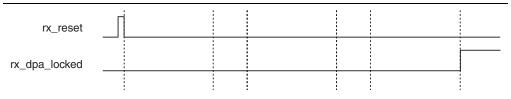


Table 37 lists the DPA lock time specifications for Stratix V devices.

Table 37. DPA Lock Time Specifications for Stratix V GX Devices Only (1), (2), (3)

| Standard | Training Pattern | Number of Data Transitions in One Repetition of the Training Pattern | Number of Repetitions per 256 Data Transitions ⁽⁴⁾ | Maximum |
|--------------------|----------------------|-------------------------------------------------------------------------------|---------------------------------------------------------------------|----------------------|
| SPI-4 | 00000000001111111111 | 2 | 128 | 640 data transitions |
| Parallel Rapid I/O | 00001111 | 2 | 128 | 640 data transitions |
| Faranei napiu 1/0 | 10010000 | 4 | 64 | 640 data transitions |
| Miscellaneous | 10101010 | 8 | 32 | 640 data transitions |
| IVIISCEIIAITEOUS | 01010101 | 8 | 32 | 640 data transitions |

Notes to Table 37:

- (1) The DPA lock time is for one channel.
- (2) One data transition is defined as a 0-to-1 or 1-to-0 transition.
- (3) The DPA lock time stated in this table applies to both commercial and industrial grade.
- (4) This is the number of repetitions for the stated training pattern to achieve the 256 data transitions.

Figure 8 shows the **LVDS** soft-clock data recovery (CDR)/DPA sinusoidal jitter tolerance specification for a data rate \geq 1.25 Gbps. Table 38 lists the **LVDS** soft-CDR/DPA sinusoidal jitter tolerance specification for a data rate \geq 1.25 Gbps.

Figure 8. LVDS Soft-CDR/DPA Sinusoidal Jitter Tolerance Specification for a Data Rate \geq 1.25 Gbps

LVDS Soft-CDR/DPA Sinusoidal Jitter Tolerance Specification

25

8.5

0.35

0.1

F1 F2

F3

F4

Jitter Frequency (Hz)

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Table 40. DQS Phase Offset Delay Per Setting for Stratix V Devices (1), (2) (Part 2 of 2)

| Speed Grade | Min | Max | Unit |
|-------------|-----|-----|------|
| C4,I4 | 8 | 16 | ps |

Notes to Table 40:

- (1) The typical value equals the average of the minimum and maximum values.
- (2) The delay settings are linear with a cumulative delay variation of 40 ps for all speed grades. For example, when using a -2 speed grade and applying a 10-phase offset setting to a 90° phase shift at 400 MHz, the expected average cumulative delay is [625 ps + (10 × 10 ps) ± 20 ps] = 725 ps ± 20 ps.

Table 41 lists the DQS phase shift error for Stratix V devices.

Table 41. DQS Phase Shift Error Specification for DLL-Delayed Clock (t_{DQS_PSERR}) for Stratix V Devices (1)

| Number of DQS Delay Buffers | C1 | C2, C2L, I2, I2L | C3, I3, I3L, I3YY | C4,I4 | Unit |
|--------------------------------|-----|------------------|-------------------|-------|------|
| 1 | 28 | 28 | 30 | 32 | ps |
| 2 | 56 | 56 | 60 | 64 | ps |
| 3 | 84 | 84 | 90 | 96 | ps |
| 4 | 112 | 112 | 120 | 128 | ps |

Notes to Table 41:

Table 42 lists the memory output clock jitter specifications for Stratix V devices.

Table 42. Memory Output Clock Jitter Specification for Stratix V Devices (1), (Part 1 of 2) (2), (3)

| Clock Network | Parameter | arameter Symbol | | 1 | C2, C2L | C2, C2L, I2, I2L C3, I3, I3L, I3YY | | | C4,I4 | | Unit |
|------------------|------------------------------|------------------------|-----------------|-----|---------|------------------------------------|-------|------|-------|------|------|
| NEIWUIK | | - | Min | Max | Min | Max | Min | Max | Min | Max | |
| | Clock period jitter | t _{JIT(per)} | -50 | 50 | -50 | 50 | -55 | 55 | -55 | 55 | ps |
| Regional | Cycle-to-cycle period jitter | t _{JIT(cc)} | -100 | 100 | -100 | 100 | -110 | 110 | -110 | 110 | ps |
| | Duty cycle jitter | $t_{JIT(duty)}$ | -50 | 50 | -50 | 50 | -82.5 | 82.5 | -82.5 | 82.5 | ps |
| | Clock period jitter | t _{JIT(per)} | -75 | 75 | -75 | 75 | -82.5 | 82.5 | -82.5 | 82.5 | ps |
| Global | Cycle-to-cycle period jitter | t _{JIT(cc)} | -150 | 150 | -150 | 150 | -165 | 165 | -165 | 165 | ps |
| | Duty cycle jitter | t _{JIT(duty)} | - 75 | 75 | -75 | 75 | -90 | 90 | -90 | 90 | ps |

⁽¹⁾ This error specification is the absolute maximum and minimum error. For example, skew on three DQS delay buffers in a −2 speed grade is ±78 ps or ±39 ps.

Table 42. Memory Output Clock Jitter Specification for Stratix V Devices (1), (Part 2 of 2) (2), (3)

| Clock | Parameter | Symbol | C1 C2 | | C2, C2L | C2, C2L, I2, I2L | | C3, I3, I3L, I3YY | | C4,I4 | |
|--------------|------------------------------|------------------------|-------|------|-------------|------------------|-----|----------------------|-----|-------|----|
| Network | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| | Clock period jitter | t _{JIT(per)} | -25 | 25 | -25 | 25 | -30 | 30 | -35 | 35 | ps |
| PHY Clock | Cycle-to-cycle period jitter | t _{JIT(cc)} | -50 | 50 | - 50 | 50 | -60 | 60 | -70 | 70 | ps |
| | Duty cycle jitter | t _{JIT(duty)} | -37.5 | 37.5 | -37.5 | 37.5 | -45 | 45 | -56 | 56 | ps |

Notes to Table 42:

- (1) The clock jitter specification applies to the memory output clock pins generated using differential signal-splitter and DDIO circuits clocked by a PLL output routed on a PHY, regional, or global clock network as specified. Altera recommends using PHY clock networks whenever possible.
- (2) The clock jitter specification applies to the memory output clock pins clocked by an integer PLL.
- (3) The memory output clock jitter is applicable when an input jitter of 30 ps peak-to-peak is applied with bit error rate (BER) -12, equivalent to 14 sigma.

OCT Calibration Block Specifications

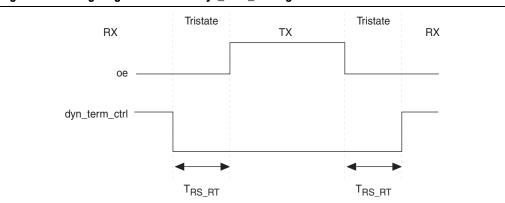
Table 43 lists the OCT calibration block specifications for Stratix V devices.

Table 43. OCT Calibration Block Specifications for Stratix V Devices

| Symbol | Description | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|--------|
| OCTUSRCLK | Clock required by the OCT calibration blocks | _ | _ | 20 | MHz |
| T _{OCTCAL} | Number of OCTUSRCLK clock cycles required for OCT $\ensuremath{R}_{\ensuremath{S}}/\ensuremath{R}_{\ensuremath{T}}$ calibration | _ | 1000 | _ | Cycles |
| T _{OCTSHIFT} | Number of OCTUSRCLK clock cycles required for the OCT code to shift out | _ | 32 | _ | Cycles |
| T _{RS_RT} | Time required between the dyn_term_ctrl and oe signal transitions in a bidirectional I/O buffer to dynamically switch between OCT R_S and R_T (Figure 10) | _ | 2.5 | _ | ns |

Figure 10 shows the timing diagram for the oe and dyn term ctrl signals.

Figure 10. Timing Diagram for oe and dyn_term_ctrl Signals



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Duty Cycle Distortion (DCD) Specifications

Table 44 lists the worst-case DCD for Stratix V devices.

Table 44. Worst-Case DCD on Stratix V I/O Pins (1)

| Symbol | C1 | | C2, C2L, I2, I2L | | C3, I3, I3L, I3YY | | C4,14 | | Unit |
|-------------------|-----|-----|------------------|-----|----------------------|-----|-------|-----|------|
| - | Min | Max | Min | Max | Min | Max | Min | Max | |
| Output Duty Cycle | 45 | 55 | 45 | 55 | 45 | 55 | 45 | 55 | % |

Note to Table 44:

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POR Delay Specification

Power-on reset (POR) delay is defined as the delay between the time when all the power supplies monitored by the POR circuitry reach the minimum recommended operating voltage to the time when the nSTATUS is released high and your device is ready to begin configuration.



For more information about the POR delay, refer to the *Hot Socketing and Power-On Reset in Stratix V Devices* chapter.

Table 45 lists the fast and standard POR delay specification.

Table 45. Fast and Standard POR Delay Specification (1)

| POR Delay | Minimum | Maximum |
|-----------|---------|---------|
| Fast | 4 ms | 12 ms |
| Standard | 100 ms | 300 ms |

Note to Table 45:

JTAG Configuration Specifications

Table 46 lists the JTAG timing parameters and values for Stratix V devices.

Table 46. JTAG Timing Parameters and Values for Stratix V Devices

| Symbol | Description | Min | Max | Unit |
|-------------------------|--------------------------|-----|-----|------|
| t _{JCP} | TCK clock period (2) | 30 | _ | ns |
| t _{JCP} | TCK clock period (2) | 167 | _ | ns |
| t _{JCH} | TCK clock high time (2) | 14 | _ | ns |
| t _{JCL} | TCK clock low time (2) | 14 | _ | ns |
| t _{JPSU (TDI)} | TDI JTAG port setup time | 2 | _ | ns |
| t _{JPSU (TMS)} | TMS JTAG port setup time | 3 | _ | ns |

⁽¹⁾ The DCD numbers do not cover the core clock network.

⁽¹⁾ You can select the POR delay based on the MSEL settings as described in the MSEL Pin Settings section of the "Configuration, Design Security, and Remote System Upgrades in Stratix V Devices" chapter.

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Table 48. Minimum Configuration Time Estimation for Stratix V Devices

| | Member Code | | Active Serial (1) |) | Fast Passive Parallel (2) | | | |
|---------|----------------|-------|-------------------|------------------------|---------------------------|------------|------------------------|--|
| Variant | | Width | DCLK (MHz) | Min Config Time (s) | Width | DCLK (MHz) | Min Config Time (s) | |
| | D3 | 4 | 100 | 0.344 | 32 | 100 | 0.043 | |
| | D4 | 4 | 100 | 0.534 | 32 | 100 | 0.067 | |
| GS | | 4 | 100 | 0.344 | 32 | 100 | 0.043 | |
| us | D5 | 4 | 100 | 0.534 | 32 | 100 | 0.067 | |
| | D6 | 4 | 100 | 0.741 | 32 | 100 | 0.093 | |
| | D8 | 4 | 100 | 0.741 | 32 | 100 | 0.093 | |
| E | E9 | 4 | 100 | 0.857 | 32 | 100 | 0.107 | |
| | EB | 4 | 100 | 0.857 | 32 | 100 | 0.107 | |

Notes to Table 48:

Fast Passive Parallel Configuration Timing

This section describes the fast passive parallel (FPP) configuration timing parameters for Stratix V devices.

DCLK-to-DATA[] Ratio for FPP Configuration

FPP configuration requires a different DCLK-to-DATA[] ratio when you enable the design security, decompression, or both features. Table 49 lists the DCLK-to-DATA[] ratio for each combination.

Table 49. DCLK-to-DATA[] Ratio (1) (Part 1 of 2)

| Configuration Scheme | Decompression | Design Security | DCLK-to-DATA[] Ratio |
|-------------------------|---------------|-----------------|-------------------------|
| | Disabled | Disabled | 1 |
| FPP ×8 | Disabled | Enabled | 1 |
| IFF X0 | Enabled | Disabled | 2 |
| | Enabled | Enabled | 2 |
| | Disabled | Disabled | 1 |
| FPP ×16 | Disabled | Enabled | 2 |
| | Enabled | Disabled | 4 |
| | Enabled | Enabled | 4 |

⁽¹⁾ DCLK frequency of 100 MHz using external CLKUSR.

⁽²⁾ Max FPGA FPP bandwidth may exceed bandwidth available from some external storage or control logic.